

PATENT APPLICATION**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re the Application of

Ichio YUDASAKA, Tatsuya SHIMODA, Sadao KANBE and Wakao MIYAZAWA

Application No.: 09/901,126

Filed: July 10, 2001

Docket No.: 040090.02

For: THIN FILM DEVICE PROVIDED WITH COATING FILM, LIQUID CRYSTAL
PANEL AND ELECTRONIC DEVICE, AND METHOD FOR MAKING THE THIN
FILM DEVICE

PRELIMINARY AMENDMENT

Director of the U.S. Patent and Trademark Office
Washington, D. C. 20231

Sir:

Prior to initial examination, please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel claims 60-81 and 84-110 without prejudice to or disclaimer of the
subject matter contained therein.

Please add new claims 111, 112 and 113 as follows:

--111. A process of forming thin film field effect transistors comprising the steps of:

forming a gate electrode on a substrate;

forming a gate insulator over said gate electrode;

forming a semiconducting layer on said insulator by ink-jet printing; and

forming source and drain contacts on said semiconducting layer.--

--112. The process of claim 111 wherein said formed semiconducting layer has a
molecular structure containing plural monomer units.--